

Claims

[c1] What is claimed is:

1. A charge pump circuit comprising a plurality of driving units cascaded in series, each driving unit comprising:
 - an input port;
 - an output port;
 - a first node;
 - a second node;
 - a first capacitor electrically connected to the first node;
 - a second capacitor electrically connected to the output port;
 - a first transistor comprising:
 - a substrate electrically connected to the second node;
 - a gate electrically connected to the output port;
 - a drain electrically connected to the input port; and
 - a source electrically connected to the first node;
 - a second transistor comprising:
 - a substrate electrically connected to the second node;
 - a gate electrically connected to the first node;
 - a drain electrically connected to the input port; and
 - a source electrically connected to the output port;
 - a third transistor comprising:
 - a substrate electrically connected to a first predeter-

mined voltage;
a gate;
a source electrically connected to the second node; and
a drain electrically connected to the output port; and
a fourth transistor comprising:
a substrate electrically connected to a second predeter-
mined voltage;
a gate;
a source electrically connected to the second node; and
a drain electrically connected to the input port;
wherein the gate of the fourth transistor within one driv-
ing unit is electrically connected to the gate of the third
transistor within previous adjacent driving unit.

- [c2] 2. The charge pump circuit of claim 1 wherein the first, second, third, and fourth transistors are p-channel metal-oxide semiconductor (PMOS) transistors.
- [c3] 3. The charge pump circuit of claim 1 wherein the first, second, third, and fourth transistors are n-channel metal-oxide semiconductor (NMOS) transistors.
- [c4] 4. The charge pump circuit of claim 1 wherein each of the first, second, third, fourth transistors comprises a triple well structure.
- [c5] 5. The charge pump circuit of claim 1 further comprising

an input unit connected to a beginning of the driving units cascaded in series, the input unit comprising:

an input port;

an output port electrically connected to the input port of the driving unit which is positioned in the beginning of the driving units cascaded in series;

a first node;

a second node;

a first capacitor electrically connected to the first node;

a second capacitor electrically connected to the output port;

a first transistor comprising:

a substrate electrically connected to a third predetermined voltage;

a gate electrically connected to the output port;

a drain electrically connected to the input port; and

a source electrically connected to the first node;

a second transistor comprising:

a substrate electrically connected to the second node;

a gate electrically connected to the first node;

a drain electrically connected to the input port; and

a source electrically connected to the output port; and

a third transistor comprising:

a substrate electrically connected to a fourth predetermined voltage;

a gate electrically connected to the first node and the

gate of the fourth transistor of the driving unit positioned in the beginning of the driving units cascaded in series;

a source electrically connected to the second node; and a drain electrically connected to the output port.

- [c6] 6. The charge pump circuit of claim 1 further comprising an output unit connected to a last of the driving units cascaded in series, the output unit comprising:
- an input port electrically connected to the output port of the last of the driving units cascaded in series;
- an output port;
- a first node;
- a first capacitor electrically connected to the input port;
- a second capacitor electrically connected to the output port;
- a first transistor comprising:
- a substrate electrically connected to the first node;
- a gate electrically connected to the input port;
- a drain electrically connected to the input port; and
- a source electrically connected to the output port; and
- a second transistor comprising:
- a substrate electrically connected to a fifth predetermined voltage;
- a gate electrically connected to the gate of the third transistor of the last of the driving units cascaded in se-

ries;
a source electrically connected to the substrate of the
first transistor; and
a drain electrically connected to the input port.